

L870-66-75

Epoxy Lens Type Infrared Illuminator

L870-66-75 is a wide viewing and extremely high output power illuminator assembled with a total of 75 high efficiency AlGaAs emitted dots, mounted on a metal stem TO-66 with AlN ceramics and covered with double coated clear silicone and epoxy resin. These devices are designed for high current operation with proper heat sinking to improve thermal conductive efficiency.

<Features>

- High Reliability
- Compact(TO-66) Package
- High Output Power at 870nm

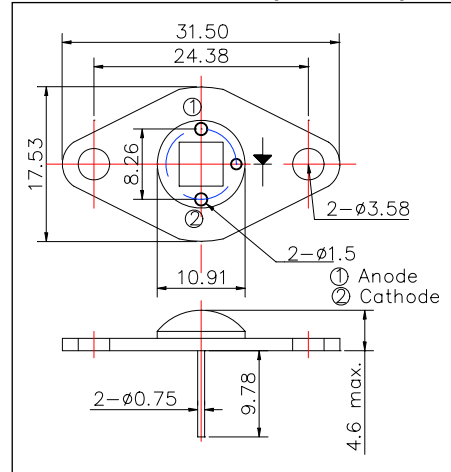
<Application>

- For IR Search Light
- For CCD Lighting
- For Night Vision Light Source

<Specifications>

1. Product Name: IR Illuminator
2. Type Number: L870-66-75
3. Chip:
 - Chip material: AlGaAs
 - Peak Wavelength: 870nm typ.
- 4.Package
 - Type: TO-66 Stem with AlN
 - Lens: Clear Silicone and Epoxy Lens

Outer Dimension (Unit:mm)



Absolute Maximum Ratings[Ta=25°C]			
Item	Symbol	Maximum Rated Value	Unit
Power Dissipation	PD	9.5	W
Forward Current	IF	1500	mA
Pulse Forward Current*	IFP	7	A
Reverse Voltage	VR	50	V
Operating Temperature	TOPR	-30 ~ +80	°C
Storage Temperature	TSTG	-30 ~ +110	°C
Soldering Temperature**	TSOL	240	°C

* Duty=1% and Pulse Width=1us

** Soldering condition must be completed within 3 second at 260°C.

Electro-Optical Characteristics						
Item	Symbol	Condition	Minimum	Typical	Maximum	Unit
Total Radiated Power	PO	IF=900mA		1600		mW
		IFP=5A		10000		
Radiant Intensity	IE	IF=900mA		450		mW/sr
Forward Voltage	VF	IF=900mA		8.0		V
Reverse Current	VR	IR=10uA	50			V
Peak Wavelength	λP	IF=900mA	860	870	880	nm
Half Width	Δλ	IF=900mA		40		nm
Viewing Half Angle	θ1/2	IF=900mA		± 60		deg
Rise Time	Tr	IF=100mA		30		ns
Fall Time	tf	IF=100mA		20		ns

Heat sink is required thermal resistance <8K/W

